Evidence for Interlayer Coupling and Moiré Periodic Potentials in Twisted Bilayer Graphene

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We report a study of the valence band dispersion of twisted bilayer graphene using angle-resolved photoemission spectroscopy and ab initio calculations. We observe two noninteracting cones near the Dirac crossing energy and the emergence of van Hove singularities where the cones overlap for large twist angles (> 5°). Besides the expected interaction between the Dirac cones, minigaps appeared at the Brillouin zone boundaries of the moiré superlattice formed by the misorientation of the two graphene layers. We attribute the emergence of these minigaps to a periodic potential induced by the moiré. These anticrossing features point to coupling between the two graphene sheets, mediated by moiré periodic potentials.

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Much effort has been directed toward using graphene in electronics and optoelectronics to exploit its high electrical conductivity and unique Dirac fermion quasiparticles [1]. With continuing progress in fabricating large-area graphene sheets, [2,3] one can now transfer one or a few graphene layers onto desired substrates [4] or construct hybrid multilayer structures [5,6]. Such transfer processes unavoidably introduce azimuthal misorientation, or twist. Many growth processes also result in twisted multilayers [7–9]. Envisioning applications involving more than one graphene sheet for specific properties [10–12] therefore makes it important to understand the electronic properties of “twisted graphene” [13].

A key issue is the electronic interaction between twisted graphene layers. Theoretical approaches have shown that, for twisted bilayer graphene (TBG), interlayer interaction occurs at discrete locations within the Brillouin zone (BZ) [14–18]. Depending on the twist angle, one can expect Fermi velocity reductions or the emergence of van Hove singularities (vHs). Transport measurements imply that TBG’s charge carriers near the Dirac crossing energy ($E_D$) behave as if in an isolated graphene sheet, confirming theoretical predictions for a large twist angle [19,20]. Scanning tunneling microscopy and Raman spectroscopy support the notion of interlayer interaction through the presence of vHs [21–23] and a moiré [24]. On the contrary, angle-resolved photoemission spectroscopy (ARPES) investigations of a similar system, twisted multilayer graphene [i.e., >two layers, typically grown on the carbon face of silicon carbide (SiC)], provided no evidence of interlayer interaction across the entire BZ [25–27], despite formation of moiré [28]. So far, ARPES has provided little information regarding the TBG’s interlayer interaction [29]. Thus, questions remain on the existence, extent, and origin of its interlayer interaction of the twisted graphene system.

We present a comprehensive picture of electronic dispersion in TBG, the simplest twisted graphene system, based on ARPES and density functional theory (DFT) calculations. We observed a band topology consisting of two noninteracting Dirac cones near $E_D$, and vHs and associated minigaps away from $E_D$, where the two layers’ Dirac cones overlap. Our experimental results provide unambiguous evidence of the interlayer interaction in TBG. What is more, we observed additional minigaps at the boundaries of the superlattice BZ associated with the moiré that evolves as two graphene lattices are rotated with respect to one another. Our results show that a moiré superlattice gives rise to a periodic potential, altering the electronic dispersion across the entire BZ according to its long-range periodicity and not just where the states from two layers overlap. These observations illustrate how electronic dispersion is modulated by the moiré, a structure ubiquitous in superimposed two-dimensional (2D) lattices (e.g., hybrid multilayer structures [5,6]).

We fabricated TBG samples by transferring graphene monolayers grown on copper foils via chemical vapor deposition [2,3,30] onto single-crystalline epitaxial graphene monolayers grown on a hydrogen-terminated SiC (0001) (Si face) [31,32] following Ref. [33]. This fabrication procedure results in >100 μm domains with random rotational orientation between two graphene lattices. Within each domain, the twist angle is relatively constant [34]. Such samples allow a systematic ARPES study of electronic dispersion primarily on a single domain with minimal effect from the underlying substrate [35]. The underlayer’s Dirac cone is fixed in momentum space ($k$ space), while the overlayer’s rotates about the $Γ$ point of the first primitive BZ, depending on the twist angle $θ$ [33]. ARPES measurements were conducted at beam line 7.0 of the Advanced Light Source [36] by using 95 eV photons, a spot size of $\sim 50 \times 100$ μm$^2$, and sample...
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11.64° is illustrated in Fig. 1(a). The red hexagon is the primitive BZ for the underlayer graphene; the blue one corresponds to the overlayer graphene. The two small half circles overlaid on Figs. 1(a) and 1(b) are the measured photoemission intensity from two Dirac cones of TBG with $\theta = 11.64°$ [43]. These intensities are the constant energy contour at 0.4 eV below $E_F$, which intersects the overlayer and underlayer cones centered at the $K$ and $K_\theta$ points, respectively [44]. Complete separation of the photoemission intensity evidences that there is no sign of interaction between the cones close to $E_D$.

The overlayer and underlayer cones exhibit slightly different spectra as seen in Fig. 1(c), which shows photoemission spectra along the line connecting $K$ and $K_\theta$ points. Owing to photoelectron attenuation, the underlayer cone (left cone at the $K$ point) displays slightly lower intensity. Moreover, although the overlayer and the underlayer graphene sheets are both p-doped, their carrier concentrations appear slightly different as evidenced by their dispersions near $E_D$. That is, the size of the overlayer Fermi surface (or the opening of the cone at $E_F$) is slightly smaller than the underlayer’s with $E_D$ at about $E_F + 0.15$ eV and $E_F + 0.2$ eV for the over- and underlayer, respectively. This small shift in $E_D$ is attributable to the smaller influence of the substrate on the overlayer, a result of screening. Correspondingly, epitaxial graphene on hydrogen-terminated SiC is slightly p-type [32,45].

Unlike near $E_D$, interactions between the two Dirac cones are observed at higher electron binding energy. Figures 2(a)–2(c) show photoemission intensity patterns at $E_F - 0.8$, $-1.0$, and $-1.3$ eV, where the contours of the cones deviate significantly from the expected circular-to-triangular band topology of monolayer graphene [46]. The superlattice BZ (black hexagon) and its high-symmetry points $\Gamma_s$, $K_s$, and $K'_s$ are overlaid on these experimental curves to highlight the superlattice’s influence on the interlayer interaction. [Note, throughout, that subscript ‘‘s’’

$T \sim 100$ K. Given the photon spot size, morphological variations at the micron scale [23] are averaged out in the ARPES measurement. Overall energy resolution was $\sim 60$ meV.

DFT calculations were conducted by using VASP [37] with the Ceperley-Alder local density functional [38], as parameterized by Perdew and Zunger [39], in the projector augmented wave approximation [40]. DFT inherently describes any interlayer electron hopping and interaction. We used a 400 eV plane-wave basis cutoff. Correspondingly, optimization of single-layer graphene yielded a C-C used a 400 eV plane-wave basis cutoff. Correspondingly, optimization of single-layer graphene yielded a C-C

$\sigma$-bond of $\approx 1.33$ Å. The electronic band structure at this twist angle was computed for comparison to the ARPES data of nominally $\theta \approx 11.6°$. We first obtained a self-consistent TBG charge density corresponding to a $9 \times 9$ equally spaced sample of the 2D superlattice BZ that included the zone center. We then computed energy levels using that density. With a bilayer separation of 3.4 Å, local density approximation forces on carbon atoms along the bilayer normal were $< 0.02$ eV/Å.

The plots shown here, calculated DFT data are shifted to align $E_D$ with the Fermi level ($E_F$), expanded by 13% in energy to account for many-body interactions [41], and adjusted for the average doping of the sample [42]. The doping level (50 meV) was estimated so that the DFT data best match the ARPES data along two high-symmetry directions [Figs. 2(d) and 2(e)]. Unequal carrier concentrations appear slightly different as evidenced by their dispersions near $E_D$. That is, the size of the overlayer Fermi surface (or the opening of the cone at $E_F$) is slightly smaller than the underlayer’s with $E_D$ at about $E_F + 0.15$ eV and $E_F + 0.2$ eV for the over- and underlayer, respectively. This small shift in $E_D$ is attributable to the smaller influence of the substrate on the overlayer, a result of screening. Correspondingly, epitaxial graphene on hydrogen-terminated SiC is slightly p-type [32,45].

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FIG. 1 (color online). $k$ space representation of TBG with $\theta \approx 11.6°$. (a) Photoemission intensity contour of the two Dirac cones at the electron energy $E_F - 0.4$ eV, and the primitive BZs of the underlayer and overlayer (red hexagon including the $K$ point and blue one including the $K_\theta$ point). Darker shades indicate higher photoemission intensities. The small black hexagon is the moiré superlattice BZ of the $(p, q) = (3, 17)$ [15] commensurate TBG. (b) Enlarged image of (a) near the two cones. (c) Photoemission spectra intersecting two cones at $K$ and $K_\theta$ points. The red (left) and blue (right) dashed lines illustrate the under- and overlayer cones, respectively, obtained by extrapolating the measured dispersions [62].

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Emergence of the anticrossing of the two bands, or minigap, formation, results from coupling between the two Dirac cones. To illustrate, Fig. 2(d) displays the photoemission spectra along the horizontal black arrow in Fig. 2(c), which bisects the two cones. Note that the \( \pi \) state is split around the \( K' \) point (cf. the red arrow). This splitting is also seen in the DFT electronic levels [blue dots in Fig. 2(d)]. The anticrossing behavior can be understood in terms of vHs, when the orthogonal direction [vertical black arrow in Fig. 2(c)] is examined. Figure 2(e) shows photoemission spectra and DFT results along this direction, where the upper “\( M'\)”-shape and the lower inverted “\( V'\)”-shape bands correspond to the left and right nested parallel bands in Fig. 2(c), respectively. By noting that the \( M'\)-shaped band in Fig. 2(e) is the same as the upper split state in Fig. 2(d), it is apparent that these states have both positive and negative masses, creating a saddle point. Thus, as a consequence of coupling between the two layers’ cones, vHs occur at the anticrossing.

Besides the vHs, faint states reside within the minigap near the red arrows in Figs. 2(c) and 2(e); however, they do not appear in the DFT calculation. We postulate that they are due to the areas where the interaction between two layers is reduced within a TBG domain. Such locations are attributable to topographical defects like ripples and blisters [47]. Low energy electron and atomic force micrographs support their presence on a length scale much smaller than our photon spot.

The photoemission intensity contours shown in Fig. 2 include an additional interacting feature not explained by direct interaction of the two layers’ Dirac cones. The green arrows in Figs. 2(b) and 2(c) highlight a splitting in the overlayer cone around the \( K'_s \) point, along a direction extending into the upper-left superlattice BZ. For more details, we take a second derivative of the photoemission intensity with respect to electron energy, as shown in Fig. 3. Red and blue circles in Fig. 3(a) highlight under- and overlayer cones and help illustrate that the new feature appears not as a consequence of these cones’ intersection but because of the presence of a “new” cone centered on the moiré superlattice \( K'_s \) point (black circle). Its dispersion is displayed in Fig. 3(b), along a line from this new (black) cone to the overlayer (blue) cone [i.e., the green arrow in Fig. 3(a)]. Similar to the vHs observed in Fig. 2(e), an additional vHs is observed in both the ARPES and DFT results in Fig. 3(b). We attribute this new cone and the additional vHs forming along with it to adiabatic umklapp scattering in the superlattice periodic potential [48,49]. They could not be present if the electrons of one layer were not responding to the periodic potential imposed by the other, thus confirming that the two graphene layers are not isolated but sense each other.

The ramifications of the periodic potential applied to graphene (in this case induced by a moiré superlattice) should have intriguing consequences [50–52]. In “normal” 2D materials, applying a periodic potential results in the isotropic opening of the minigap over the entire boundary of the minizone defined by the potential’s periodicity. Graphene’s response is quite different because of the chiral (pseudospin) nature of the wave functions.
FIG. 3 (color online). Second derivative of the ARPES intensity with respect to the energy ($\theta \approx 11.6^\circ$). (a) Contours at $E_F - 0.8$ eV. The black hexagons are the superlattice BZ. The red, blue, and black circles with “U”, “O,” and “M” illustrate the locations of underlayer, overlayer, and moiré superlattice Dirac cones, respectively. (b) Processed photoemission pattern along the green arrow in (a) and DFT states (blue dots) connecting $K'$, $K''$, and $K$ points. Circles (green) highlight DFT states matching the ARPES data.

Accordingly, the periodic potential does not open the minigap along the entirety of the minizone boundary but only at certain locations. Thus, moving along the minizone boundary, gaps will emerge and disappear.

To examine this effect, following Park et al. [51], we define the minizone [green hexagons in Fig. 2(a)] by translating the superlattice BZ, so the center of the superlattice BZ matches $K$ and $K'$ points. The line connecting $K'$ and $\Gamma$ points is along the minizone boundary [53]. In this view, coexistence of band splitting and crossing [shown by ARPES and DFT, red and blue arrows in Fig. 2(d)] is a consequence of the periodic potential induced by the moiré superlattice. Hence, the nonconstant gap occurs because of graphene’s chiral wave functions.

Supporting this conclusion, the periodic potentials of a moiré should vary on a much longer length scale than the interatomic distance. Thus, a slight shift of one graphene sheet relative to another should only affect the electronic dispersion of TBG weakly. DFT calculations involving translations of one of the two graphene sheets by a fraction of interatomic distance confirm this. We conclude that TBG’s electronic dispersion evolves from two rotated graphene sheets subject to a long-range potential of the moiré superlattice evolving between them. Alternatively, TBG comprises two graphene sheets, each subject to a periodic potential. This provides a simple way to understand many of the unique features alluded to in previous theoretical studies [51,52].

Incidentally, the additional interacting state does not appear at the underlayer cone highlighted by the red circle in the data presented but did appear in other data for different (typically smaller) twist angles [54]. If there is yet another new Dirac cone present in Fig. 3(a), we expect it to be centered on $k_x \sim 1.4$ Å$^{-1}$, $k_y \sim -0.34$ Å$^{-1}$ and have the band topology similar to the new cone highlighted by the black circle. Although there is a state near where we expect to see the new cone, its shape is quite different. We therefore suspect that the data at the lower $k_y$ in Fig. 3(a) originate from another TBG domain having a slightly different twist angle.

Regions of $AB$ stacking in the moiré superlattice dominate the interlayer interaction for twist angles $>5^\circ$ [18], resulting in the minigaps seen in Fig. 4. Figures 4(b) and 4(d) show the energy distribution curves (EDCs) halfway between the $K$ and $K'$ points. For twist angles of $5^\circ$ to $12^\circ$, the energy separation (peak-to-peak) stays near $-0.2$ eV (cf. the red arrows). This value is of the same order of magnitude as the interlayer interaction parameter of Bernal bilayer graphene, $\sim 0.4$ eV [55]. We attribute the relatively unvarying magnitude of the minigap with twist angle to the persistence of local $AB$ stacking within the moiré [56]. The large real-space moiré superlattice ensures the existence of $AB$ stacking for all twist angles.

Last, we offer plausible rationales for the absence of some of our DFT energy levels in the corresponding ARPES data [see small blue dots in Figs. 2(d), 2(e), and 3(b)]. First, the structure factor associated with ARPES may preferentially increase the intensity of certain states. This has been observed in measurements wherein intensities are strongly enhanced when a surface state overlaps a bulk state in $k$ space [57]. Following this argument, we presume that the TBG states overlapping those of a noninteracting graphene sheet would appear strongly in the ARPES measurement. Consequently, the measured photoemission intensity matches only a small subset of the DFT calculated states. Disorder in the TBG including mechanical distortions provides another possibility. As we saw via low energy electron diffraction, the twist angle in our samples varied...
sion and thus the properties of the multilayer stack. Because of the small superlattice BZ, the experimentally observed states from slightly different twist angles would be broadened with their intensity decaying rapidly, especially for those created by folding at superlattice BZ boundaries. The likelihood of observing these folded states would decrease correspondingly.

Coupling between the electronic states and the superlattice periodic potential have important implications for twisted multilayer graphene and hybrid 2D multilayer stacks. Based on our study of TBG, the superlattice BZ of a multilayer graphene (> three layers) is expected to be smaller (thus longer periodicity in real space). Previous theoretical work has shown that, with an increase in spatial period, the apparent minigap shrinks [51], leading to effectively noninteracting states. This is consistent with reported experimental results [27]. Second, any hybrid multilayers based on transferring 2D materials will unavoidably induce moiré superlattices and thus subject the system to a periodic potential. This potential influences the dispersion and thus the properties of the multilayer stack. Although transfer techniques now offer the possibility of a wider class of 2D materials [59,60] much as heteroepitaxial growth does [61], understanding how these layers change as they are stacked together and mutually interact is prerequisite to leveraging their properties.

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[30] Graphene monolayers grown on copper foils via chemical vapor deposition typically consist of domains of a few hundred micrometers in size with random orientations.
Using low energy electron microscopy and diffraction, we determined that the twist angle within each domain can vary up to 1° and typically has ±0.5° variation over a few to tens of micrometers length scale.


Scienta R4000 electron energy analyzer.


The twist angle is estimated from the ARPES data. The measured photoemission intensity is suppressed on one side of the BZ due to interference effects between the two equivalent sublattices in graphene. E.L. Shirley, L.J. Terminello, A. Santoni, and F.J. Himpsel, Phys. Rev. B 51, 13 614 (1995).

The other cones located at the corners of primitive BZs (K, K', K_0, and K'_0 points) are not shown due to the limited k space of the measurement.


A faint state around E_F = 0.3 eV in the left Dirac cone at the K point (underlayer) reflects a small coverage of the second layer in epitaxial graphene.